## Single Crystal Niobium Technology Workshop

CBMM, Araxà, Brazil, October 30 – November 1, 2006



## Overview of ILC

### **Carlo Pagani** University of Milano INFN Milano-LASA & GDE

# Energy Frontier and Accelerator Tech.



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006





$$E = m c^2$$

Momentum 
$$\boldsymbol{p} = \boldsymbol{m} \, \boldsymbol{v} \approx \, m_0 \, \boldsymbol{\gamma} \, \boldsymbol{c}$$

Kinetic energy

 $K = E - E_0 = (\gamma - 1) m c^2$ 

Speed of light:  $c = 2.9979 \cdot 10^8 \text{ ms}^{-1}$ Energy unit:  $1 \text{ eV} = 1.6021 \cdot 10^{-19} \text{ J}$  Electron rest energy:  $E_0 = 0.511 \text{ MeV}$ Proton rest energy:  $E_0 = 938 \text{ MeV}$ 

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

### RF acceleration: Synchrotron The LEP Example







#### Strong focusing concept



### For $v \approx c \longrightarrow E[GeV] \approx 0.3 B[T] \cdot \rho[m]$

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

IIL

# No Circular e<sup>+</sup>e<sup>-</sup> Collider after LEP

### Synchrotron Radiation: charged particle in a magnetic field:



Energy loss dramatic for electrons

$$U_{SR} \left[ \text{GeV} \right] = 6 \cdot 10^{-21} \cdot \gamma^4 \cdot \frac{1}{r[km]}$$

 $U_{SR}$  = energy loss per turn  $\gamma$  = relativistic factor r = machine radius

$$\gamma_{\text{proton}} / \gamma_{\text{electron}} \approx 2000$$

Energy loss replaced by RF power cost scaling  $\$ \propto E_{cm}^{2}$ 

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

- Both size and power seem excessive
- power than the state of California in summer: ~ 45 GW
- 13 GeV/turn x 2 amperes = 26 GW RF power - Because of conversion efficiency, this collider would consume more
- For a luminosity of ~  $10^{34}$ /cm<sup>2</sup>/second, scaling from b-factories gives ~ 1 Ampere of beam current Circulating beam power = 500 GW
- Consider also the luminosity
- Possible scale to 250 GeV/beam i.e. E<sub>cm</sub> = 500 GeV: 170 km around

Single Crystal Nb Tech. Ws

Araxà, Brazil, 30 Oct 2006

IIL

- 13 GeV/turn lost

- RF system must replace this loss, and r scale as  $E^2$

- LEP @ 100 GeV/beam: 27 km around, 2 GeV/turn lost

 $U_{SR}[GeV] = 6 \cdot 10^{-21} \cdot \gamma^4 \cdot \frac{1}{r[km]}$ 

A Simple Exercise



 $\gamma_{250GeV}$  = 4.9 . 10<sup>5</sup>

6

## LC conceptual scheme



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİĹ

## Fighting for Luminosity



### Parameters to play with

Reduce beam emittance  $(\varepsilon_x \cdot \varepsilon_y)$  for smaller beam size  $(\sigma_x \cdot \sigma_y)$ Increase bunch population  $(N_e)$ Increase beam power  $(P_b \propto N_e \times n_b \times f_{rep})$ Increase beam to-plug power efficiency for cost

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Competing technologies for the ILC

### Evolution from: SLAC & SLC



+ hundreds for research & application

### 1.3 GHz - Cold

;lr iit

### Evolution from: CEBAF & LEPII

+ TRISTAN, HERA, etc.





11.4 GHz - Warm

30 GHz-Warm

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

### January 2003

ilc

### $E_{cm}$ = 500 GeV

	-	TESL A	SBLC	JLC- S	JLC- C	JLC-X/NLC	VLEPP	CLIC
f	[GHz]	1.3			5.7	11.4		30.0
<b>ل</b> ×10 <sup>3</sup>	<sup>3</sup> [cm <sup>-2</sup> s <sup>-</sup>	34			14	20		21
P <sub>beam</sub>	[MW]	11.3			5.8	6.9		4.9
P <sub>AC</sub>	[MW]	140			233	195		175
$\gamma \varepsilon_{y}^{8}$ m]	[×10 <sup>-</sup>	3			4	4		1
<b>o</b> <sub>y</sub> *	[nm]	5			4	3		1.2

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

### **Beam Sizes**



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## LC Organisation up to August 2004



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ilr

### **The Recommendation**

İİĹ

- We recommend that the linear collider be based on superconducting rf technology (from Exec. Summary)
  - This recommendation is made with the understanding that we are recommending a technology, not a design. We expect the final design to be developed by a team drawn from the combined warm and cold linear collider communities, taking full advantage of the experience and expertise of both (from the Executive Summary).
  - We submit the Executive Summary today to ILCSC & ICFA
  - Details of the assessment will be presented in the body of the ITRP report to be published around mid September
  - The superconducting technology has features that tipped the balance in its favor. They follow in part from the low rf frequency.

19-Aug-04ITRP - LC Technology Recommendation13Single Crystal Nb Tech. WsCarlo PaganiAraxà, Brazil, 30 Oct 2006

### Some of the Features of SC Technology

- The large cavity aperture and long bunch interval reduce the complexity of operations, reduce the sensitivity to ground motion, permit inter-bunch feedback and may enable increased beam current.
- The main linac rf systems, the single largest technical cost elements, are of comparatively lower risk.
- The construction of the superconducting XFEL free electron laser will provide prototypes and test many aspects of the linac.
- The industrialization of most major components of the linac is underway.
- The use of superconducting cavities significantly reduces power consumption.

Both technologies have wider impact beyond particle physics. The superconducting rf technology has applications in other fields of accelerator-based research, while the X-band rf technology has applications in medicine and other areas.

g-04 ITRP - LC Technology Recommendation

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİL

Carlo Pagani

14

## ILC Pictorial View (TESLA Like)



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ir

## Start of the Global Design Initiative



ilC

### First ILC Workshop

Towards an International Design of a Linear Collider

November 13th (Sat) through 15th (Mon), 2004 KEK, High Energy Accelerator Research Organization 1-1 Oho, Tsukuba, Ibaraki 305-0801, Japan

> Program Committee: Kacru Yokeya (KEK), Hitoshi Hayano (KEK), Kenji Satio (KEK), David Burke (SLAC), Steve Holmes (FNAL), Gerald Dugan (Cornell), Nick Walker (DESY), Jean-Pierre Delahaye (CERN), Oliver Napoli (CEA/SacJay)



Local Organizing Committee: Yoji Totsuka (KEK)(Char), Fumihiko Takasaki (KEK)(Deputy-chair), Junji Urakawa (KEK), Kiyoshi Kubo (KEK), Shigeru Kuroda (KEK), Nobuhiro Terunuma (KEK), Toshiyasu Higo (KEK), Tsunehiko Omori (KEK), Toshiaki Tauchi (KEK), Akiya Miyamoto (KEK), Masao Kuriki (KEK), Kiyosumi Tsuchiya (KEK), Shuichi Noguchi (KEK), Ejii Kako (KEK)

International Advisory Committee: Robert Aymar (CERN), Albrecht Wagner (DESY), Michael Witherell (FNAL), Yoği Totsuka (KEK), Jonathan Dorfan (SLAC), Won Namkung (PAL), Brian Foster (Oxford), Maury Tigner (Comell), Hesheng Chen (IHEP), Alexander Skrinsky (BINP), Carlos Garcia Canal (UNLP), Sachio Komamiya (Tokyo), Paul Grannis (SUNY)

http://lcdev.kek.jp/ILCWS/

### ~ 220 participants from 3 regions most of them accelerator experts

## Global Design Effort (GDE)

On March 18, 2005, during the opening of *LCWS05* workshop at Stanford University, **Barry Barish** officially accepted the position of Director of the **G**lobal Design Effort, **GDE** (yet to be formed)



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

;|r iit



## **GDE** Actual Members



Hasan Padamsee Cornell

University

Dieter Proch

Peter Garbincius FNAL LAL - IN2P3

Maxine S. Hronek GDE/Fermilab



Marc Ross SLAC





Andrei Servi SLAC John SLAC





Sasha Skrinsky Budker Institute Pohang of Nuclear Physics Laboratory





Nobu Toae













Ewan Paterson SLAC SLAC

67 **49** 

Kaoru Yokoya KEK

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

Warren Funk

Susanna Guiduce

Jie Gao IHEP

Hitoshi Hayano Tom Hi KFK SLAC

Carlo Pagani

Carlo Pagani University of Milano

Pantaleo Raimondi INFN

## Linacs are made of RF cavities

 To give energy to a charged particle beam, apart from "details", you need to let him move across a region in which an electric field exists and is directed as the particle motion.

$$\Delta E_{particle} = \int \vec{F}_{Lorentz} \cdot d\vec{s} = q \int \vec{E} \cdot \vec{v} dt$$

- In the accelerator's world RF take care of all the variety of items that are required to accomplish this task of creating a region filled of electromagnetic energy that can be sucked by the beam while crossing it.
- An "RF power source" is used to fill, via a "coupler", the "RF cavity", or resonator that is the e.m. energy container from which the beam is taking its energy.
- What we ask to a good cavity?

### High Q for losses: U = stored energy $P_{diss}$ = dissipated power



Small  $R_s$  for high Q:  $R_s$  = surface resistance G = cavity geometrical factor

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Why Cold RF ?



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

IIL

## The ILC technology choice

Standing wave:  $V_{ph} = 0$  and Vg = c



The power is deposited at the operating temperature of 2  $\rm K$ 

We need to guarantee and preserve the 2 K environment

 Cavity is sensitive to pressure variations, only viable environment is sub-atmospheric vapor saturated He II bath

We need a thermal "machine" that performs work at room temperature to extract the heat deposited at cold

• We can't beat Carnot efficiency!

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006 Remembering that the power dissipated on the cavity walls to sustain a field is:

$$P_{diss} = \frac{R_s}{2} \int_{S} H^2 dS$$

standing wave case

a pulsed operation is required to reduce the time in which the maximum allowable field is produced to accelerate the particles



### Cryogenics and cryomodules

## How is spent the cold advantage?

The gain in RF power dissipation with respect to a normal-conducting structure is spent in different ways

- Paying the price of supplying coolant at 2K
  - This include ideal Carnot cycle efficiency
  - Mechanical efficiency of compressors and refrigeration items
  - Cryo-losses for supplying and transport of cryogenics coolants
  - Static losses to maintain the linac cold
- Increasing of the duty cycle (percentage of RF field on)
  - Longer beam pulses, larger bunch separation, but also
  - Larger and more challenging Damping Rings
- Increasing the beam power (for the same plug power)
  - Good for Luminosity

İİL

 $W \ge Q \frac{T_h - T_c}{T_c}$ 

$$R_{s} = \frac{A \omega^{2}}{T} \exp\left(-\frac{\Delta}{k_{B}T}\right) + R_{res}$$

- Constant  $R_{res}$  at  $T \rightarrow 0$  for small  $H_0$  is inconsistent with the BCS theory
- Mechanisms of R<sub>res</sub> are likely unrelated to superconductivity
- Field, temperature and frequency dependences of R<sub>res</sub> are poorly understood
- Effect of surface oxides (hydrides) or more fundamental mechanisms?

 $R_{res} \approx 1-20 \ n\Omega$ 



Figure 16. Measured temperature dependence of the surface resistance of a Nb cavity at 1.3 GHz. In this semi-log plot, the linear region gives an energy gap of  $\Delta = 1.9kT_c$ . The residual resistance is 3 n $\Omega$ .



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Other Physical Limits



Critical Magnetic Field Limit

Figure 10: Critical RF fields (Hcf) of sc cavities and Hsh.

## $B_{max} \leq 180 \text{ mT}$

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİĻ

Carlo Pagani

### Vortex state of trapped Magnetic Field



### Limited thermal conductivity

- Thermal Conductivity of the bulk Nb
- Kapitza resistance at the surface



# Low Field Quenches: Surface Defects

### For decades Niobium has been a by-product of Tantalum production













Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## SRF before TESLA



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

### Poor material properties

- Moderate Nb purity (Niobium from the Tantalum production)
- Low Residual Resistance Ratio, RRR —> Low thermal conductivity
- Normal Conducting inclusions —> Quench at moderate field

### Poor cavity treatments and cleanness

- Cavity preparation procedure at the R&D stage
- Poor rinsing and clean room assembly not yet introduced

### Microphonics

İİL

Mechanical vibrations in low beta structures — High RF power required

### Multipactoring

- Major limit for HEPL and electron linacs to 1984
- Poor codes and surface status

### Quenches/Thermal breakdown

• Low RRR and NC inclusions

### Field Emission

• General limit at those time because of poor cleaning and material defects

## **R&D** waiting for big projects

### Multipactoring

**11L** 

- A few computer codes developed
- Spherical shape realized at Genova and qualified at Cornell & Wuppertal

### Field Emission

- Emitters were localized and analyzed
- Improved treatments and cleanness

### Quenches/Thermal Breakdown

• Higher RRR Nb





### 1984/85: First great success

- A pair of 1.5 GHz cavities developed and tested (in CESR) at Cornell
- Chosen for CEBAF at TJNAF for a nominal E<sub>acc</sub> = 5 MV/m

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Large Project Impact on SRF

- The decision of applying this unusual technology in the largest HEP and NP accelerators forced the labs to invest in Research & Development, infrastructures and quality control
- The experience of industry in high quality productions has been taken as a guideline by the committed labs
- At that time TJNAF and CERN played the major role in SRF development, mainly because of the project size
- The need of building hundreds of cavities pushed the labs to transfer to Industry a large part of the production
- The large installations driven by HEP and NP produced a jump in the field
- R&D and basic research on SRF had also a jump thanks to the work of many groups distributed worldwide





Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİL

## CEBAF and LEP II

### CEBAF

ilr

İİL

### 338 bulk niobium cavities

- Produced by industry
- Processed at TJNAF in a dedicated infrastructure





### LEP II & CERN

- 32 bulk niobium cavities
  - Limited to 5 MV/m
  - Poor material and inclusions

### 256 sputtered cavities

- Magnetron-sputtering of Nb on Cu
- Completely done by industry
- Field improved with time
   <E<sub>acc</sub>> = 7.8 MV/m (Cryo-limited)

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Important technological steps

- Use of the best niobium (and copper) allowable in the market at the time
- Industrial fabrication of cavity components with high level quality control
- Assembly of cavity components by Industry via Electron Beam welding in clean vacuum
- Use of ultra pure water for all intermediate cleaning
- Use of close loop chemistry with all parameters specified and controlled
- Cavity completion in Class 100 Clean Room
  - Final water cleaning and drying (UV for bacteria and on line resistivity control)
  - Integration of cavity ancillaries

### That is

### New level on Quality Control

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİL





A great success for LEP II



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

iļŗ

ΪĿ

## The TESLA Collaboration Mission

### Develop SRF for the future TeV Linear Collider

### **Basic** goals

İİL

- Increase gradient by a factor of 5 (Physical limit for Nb at ~ 50 MV/m)
- Reduce cost per MV by a factor 20 (New cryomodule concept and Industrialization)
- Make possible pulsed operation (Combine SRF and mechanical engineering)

### Major advantages vs NC Technology

- Higher conversion efficiency: more beam power for less plug power consumption
- Lower RF frequency: relaxed tolerances and smaller emittance dilution



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

# TESLA Coll. Milestones up to 08/2004

- February 1992 1° TESLA Collaboration Board Meeting @ DESY
- March 1993 "A Proposal to Construct and Test Prototype Superconducting RF Structures for Linear Colliders"
- 1995 25 MV/m in multi-cell cavity
- May 1996 First beam at TTF
- March 2001 First SASE-FEL Saturation at TTF
- March 2001 TESLA Technical Design Report
- February 2003 TESLA X-FEL proposed as an European Facility, 50% funding from Germany
- 2004 TTF II Commissioning start
- April 2004 35 MV/m with beam
- August 2004 TESLA Technology chosen for ILC



## TESLA cavity design and rules

### Major contributions from: CERN, Cornell, DESY, CEA-Saclay, INFN

• 9-cell, 1.3 GHz

ilC





#### **TESLA** cavity parameters

R/Q	1036	Ω
E <sub>peak</sub> /E <sub>acc</sub>	2.0	
B <sub>peak</sub> /E <sub>acc</sub>	4.26	mT/(MV/m)
$\Delta f/\Delta I$	315	kHz/mm
K <sub>Lorentz</sub>	≈ -1	Hz/(MV/m) <sup>2</sup>





Eddy-current scanning system for niobium sheets

Cleanroom handling of niobium cavities

#### **Preparation Sequence**

- Niobium sheets (RRR=300) are scanned by eddy-currents to detect avoid foreign material inclusions like tantalum and iron
- Industrial production of full nine-cell cavities:
  - Deep-drawing of subunits (half-cells, etc. ) from niobium sheets
  - Chemical preparation for welding, cleanroom preparation
  - Electron-beam welding according to detailed specification
- 800 °C high temperature heat treatment to stress anneal the Nb and to remove hydrogen from the Nb
- 1400 °C high temperature heat treatment with titanium getter layer
- to increase the thermal conductivity (RRR=500)
- Cleanroom handling:
  - Chemical etching to remove damage layer and titanium getter layer
  - High pressure water rinsing as final treatment to avoid particle contamination

## TTF: a new infrastructure at DESY



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ilr

# Eddy Current Scanner for Nb Sheets



### Scanning results



- Rolling marks and defects are visible on a niobium disk to be used to print a cavity half-cell.
- Surface analysis is then required to identify the inclusions

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Chemistry, HPR and String Assembly



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Learning curve with BCP

### BCP = Buffered Chemical Polishing

**3 cavity productions from 4 European industries: Accel, Cerca, Dornier, Zanon** 4<sup>th</sup> production of 30 cavities concluded, also to define Quality Control for Industrialization



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## 3<sup>rd</sup> cavity production with BCP



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ΪĹ

## EP & Baking for 35 MV/m

### Electro-Polishing (EP)

instead of Buffered Chemical Polishing (BCP)

IIL

- less local field enhancement
- High Pressure Rinsing more effective
- Field Emission onset at higher field

### In Situ Baking

@ 120-140 ° C for 24-48 hours

- to re-distribute oxygen at the surface
- cures Q drop at high field



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## LCH and ILC Module Comparison







Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ilc



- TESLA Test Facility (TTF II) @ DESY TTF II is currently unique in the world VUV-FEL user facility (now called FLASH) test-bed for both XFEL & ILC Cryomodule Test Stand under commissioning
- SMTF @ FNAL
  - Cornell, JLab, ANL, FNAL, LBNL, LANL, MIT, MSU, SNS, UPenn, NIU, BNL, SLAC TF for ILC, Proton Driver, RIA (and more)
- STF @ KEK

aggressive schedule to produce high-gradient (45MV/m) cavities / cryomodules

• Others?

## TTF II - FLASH @ DESY

### FLASH (VUV-FEL) as XFEL Prototype



ilr iit











Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

Carlo Pagani

m

## Cryomodule Test Stand @ DESY





### feed cap transfer line

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ilc

### STF @ KEK



#### Plan of Superconducting Cavity Test Facility (STF)

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ΪĹ

Carlo Pagani

V2.1 Hitoshi Havano, 11/03/2004

## SMTF @ FNAL as presented to DOE

#### FNAL Meson Area SM&TF Layout Concept



"The SMTF proposal is to develop U.S. Capabilities in high gradient and high Q superconducting accelerating structures

in support of

#### International Linear Collider Proton Driver RTA

4th Generation Light Sources Electron coolers lepton-heavy ion collider and other accelerator projects of interest to U.S and the world physics community."

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## One Industrial Forum in Each Region



İİĹ





## Summary of findings & discussion: Industry forum

- Industry Fora about SC accelerator technology in all 3 regions
  - Asia: operating since 2 years
  - Europe: under formation
  - USA: under planning Both Operational
- All with strong local commitment
  - Critical to secure funds for ILC from ministries in all regions
  - Strong local commitment might be necessary at this moment because of differences in technical expertise and political boundary conditions
  - But: danger of too large diversity in technology/design: Is the 1/3 linac per region the right approach for ILC?

Summary Industrialization Sympossium, SRF 2005, D.Proch

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## European Industrial Forum for SCRF



https://indico.desy.de/conferenceTimeTable.py?confId=61

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006 Carlo Pagani

İİĻ

## Great Impulse from TESLA Results

- High Energy Physics: Leptons and Hadrons
  - ILC is growing cold
  - 8 GeV Proton Driver for FNAL
  - SPL for CERN: neutrinos and LHC upgrade
  - Electron coolers
  - .....

ilr iit

- Nuclear Physics: Ions and Electrons
  - Spiral 2
  - RIA
  - Eurisol
  - Spes
  - CEBAF Upgrade
  - .....
- Applied Physics: Electrons
  - Spallation Neutron Sources: SNS
  - 4th Generation Light Sources: European X-FEL
  - Storage Rings
  - Energy Recovery Linacs: 4GLS in Europe and many others
  - .....
- ADS for Nuclear Waste Transmutation
  - EuroTrans

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006











- Produce a design for the ILC that includes a detailed design concept, performance assessments, reliable international costing, an industrialization plan, siting analysis, as well as detector concepts and scope.
- Coordinate worldwide prioritized proposal driven R & D efforts (to demonstrate and improve the performance, reduce the costs, attain the required reliability, etc.)

© Barry Barish

## Parametric Approach

### A working space - optimize machine for cost/performance



		min		nominal		max	
Bunch charge	N	1	-	2	-	2	$\times 10^{10}$
Number of bunches	$n_b$	1330	-	2820	-	5640	
Linac bunch interval	$t_b$	154	-	308	-	461	ns
Bunch length	$\sigma_z$	150	-	300	-	500	μm
Vert.emit.	$\gamma \epsilon_y^*$	0.03	-	0.04	-	0.08	mm∙mrad
IP beta (500GeV)	$\beta_x^*$	10	-	21	-	21	mm
	$\beta_y^*$	0.2	-	0.4	-	0.4	mm
IP beta (1TeV)	$\beta_x^*$	10	-	30	-	30	mm
	$\beta_y^*$	0.2	-	0.3	-	0.6	mm

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ΪĹ

## Designing a Linear Collider



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİĻ

## Making Choices - The Tradeoffs



Many decisions are interrelated and require input from several WG/GG groups

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ilc

## From Snowmass to a Baseline



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Structure of the BCD



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİİ

## **Alternatives Section**



## ACD is part of the BCD

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ίiί

## Baseline/Alternative: some definitions

Baseline: a forward looking configuration which we are reasonably confident can achieve the required performance and can be used to give a reasonably accurate cost estimate by mid-end 2006 (→ RDR)

### Alternate: A technology or concept which may provide a significant cost reduction, increase in performance (or both), but which will not be mature enough to be considered baseline by mid-end 2006

### Note:

Alternatives will be part of the RDR Alternatives are equally important

## Single Crystal Niobium is a crucial alternative

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006



- Selected some selected new members for the GDE following the BCD completion who have needed skills in design, engineering, costing, etc
- Change Control Board
  - The baseline will be put under configuration control and a Board with a single chair will be created with needed expertise.
- Design / Cost Board
  - A GDE Board with single chair will be established to coordinate the reference design effort, including coordinating the overall model for implementing the baseline ILC, coordinating the design tasks, costing, etc.
- R&D Board
  - A GDE Board will be created to evaluate, prioritize and coordinate the R&D program in support of the baseline and alternatives with a single chair

## From Baseline to a RDR

iļŗ

İİĻ

Araxà, Brazil, 30 Oct 2006



## SRF Cavity Gradient

	Cavity type	Qualified gradient	Operational gradient	Length*	energy	
		MV/m	MV/m	Km	GeV	
initial	TESLA	35	31.5	10.6	250	
upgrade	LL	40	36.0	+9.3	500	

Total length of one 500 GeV linac  $\approx$  20km (\* assuming 75% fill factor)



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ic

# ILC Gradient and the R&D on Shapes

- 35MV/m is close to optimum
- 30 MV/m would give safety margin



### KEK is pushing for 40-45MV/m "ICHIRO" cavity

Larger magnetic volume:

- Lower peak magnetic field
- Lower cryogenic losses
- But: higher field emission?



Low Loss Shape LL





Cornell and JLab are also testing low B geometries

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## TTF: Raw data for trends



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

ilc



Radiation Dose from the fully equipped cavities while High Power Tested in "Chechia" "Chechia" is the horizontal cryostat equivalent to 1/8 of a TTF Module



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

# JLab is driving an essential R&D on Nb

- Niobium quality remains the major issue to completely understand and define Quality Control & Quality Assurance parameters
- Most of the niobium cost is determined by the effort of preserving quality through casting rolling and heat treatments required for "homogenous" grain and reasonable isotropy
- Many producer could deliver pure Nb at the ingot state but few can supply sheets with the required minimal properties



Microstructure is Heterogeneous (Banded)

Crystal grains change with the 800 °C heat treatment for dehydrogenization and stress release

#### As received

After 800 °C annealing

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Grain Problems in nowadays Niobium

### Niobium sheet cut after the 800 ° annealing. Colors refers to crystal orientations





Grain size grow and orientation depend from the batch used and varies from sheet to sheet of the same batch

Define QC and QA for the required mechanical properties is a concern

Cavity shape and treatment results are effected by this heterogeneity, grain boundaries and their orientation

Inclusions or clusters in the bulk at the several  $\mu m$  level are not detectable

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

# Large or Single Crystals are promising

- Peter Kneisel at JLab is leading a collaboration that try to qualify niobium sheets obtained by EDM (Electron Discharge Machining) directly from the ingot
- Preliminary results are very promising
- In case of success, material QC and QA would be much easier and the cost possibly cheaper





2.2 GHz Single crystal single cell cavity

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

# Major Cost drivers in Main Linac



Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

## Cryomodule cost estimation



Cavity Fabrication cost includes cost of materials
\*\* Facilities costs are included in each item

Single Crystal Nb Tech. Ws Araxà, Brazil, 30 Oct 2006

İİL

## From Basic Research to Industry

- High Energy Physics is pushing the limits of Acc. Technology
  - Goals beyond the actual technology limits
  - Large, internationally supported, projects
  - Strong participation from Industry
  - Strict Requirements on Quality Assurance and Quality Control
- Other science fields are applying results and making progress
  - Future energy plants: Fusion and Nuclear Waste Transmutation
  - Spallation Neutron Sources
  - Synchrotron Light Sources
  - Free Electron Lasers
  - Humane Science: Medicine and Biology
- Industry took benefit from supported R&D
  - Industrial and medical applications of SLAC type linacs
  - Medical applications of Superconducting Magnets
  - and many other examples